

## Switchmode Full Plastic Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with high temperature operation metal. The proprietary barrier technology allows for reliable operation up to 150°C junction temperature. Typical applications are in switching Mode Power Supplies such as adaptors, Photovoltaic Solar cell protection, free-wheeling and polarity protection diodes.

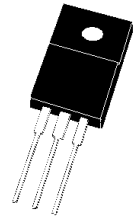
### Features

- \* Ultra Low Forward Voltage.
- \* Low Switching noise.
- \* High Current Capacity
- \* Low Power Loss & High efficiency.
- \* 150°C Operating Junction Temperature
- \* Low Stored Charge Majority Carrier Conduction.
- \* Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- \* Pb free
- \* In compliance with EU RoHs directives

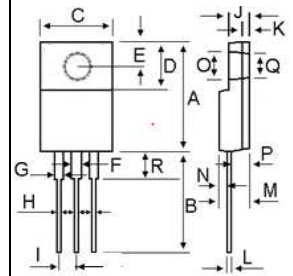


### SCHOTTKY BARRIER RECTIFIERS

**20 AMPERES  
60 VOLTS**



**ITO-220AB**



DIM	MILLIMETERS	
	MIN	MAX
A	14.80	16.10
B	12.65	14.40
C	9.70	10.36
D	4.60	6.80
E	2.50	3.50
F	0.90	1.45
G	0.90	1.45
H	0.50	0.90
I	2.40	2.70
J	2.34	3.30
K	0.55	1.30
L	0.36	0.80
M	4.20	4.90
N	1.10	1.80
O	2.90	3.50
P	2.30	3.15
Q	2.90	3.50
R	2.80	4.85

### MAXIMUM RATINGS

Characteristic	Symbol	S20M60F	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	60	V
RMS Reverse Voltage	$V_{R(RMS)}$	42	V
Average Rectifier Forward Current ( per diode ) Total Device (Rated $V_R$ ),	$I_{F(AV)}$	10 20	A
Peak Repetitive Forward Current (Rate $V_R$ , Square Wave, 20kHz)	$I_{FM}$	20	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	$I_{FSM}$	200	A
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +150	°C

### THERMAL RESISTANCES

Typical Thermal Resistance junction to body	$R_{\theta jc}$	6.5	°C/w
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### ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Maximum Instantaneous Forward Voltage ( $I_F = 10.0$ Amp $T_C = 25^\circ C$ ) ( $I_F = 10.0$ Amp $T_C = 125^\circ C$ )	$V_F$	---	0.53 0.52	0.55 ---	V
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C = 25^\circ C$ ) ( Rated DC Voltage, $T_C = 125^\circ C$ )	$I_R$	---	0.08 30	0.15 ---	mA

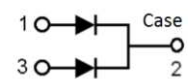


FIG-1 FORWARD CURRENT DERATING CURVE

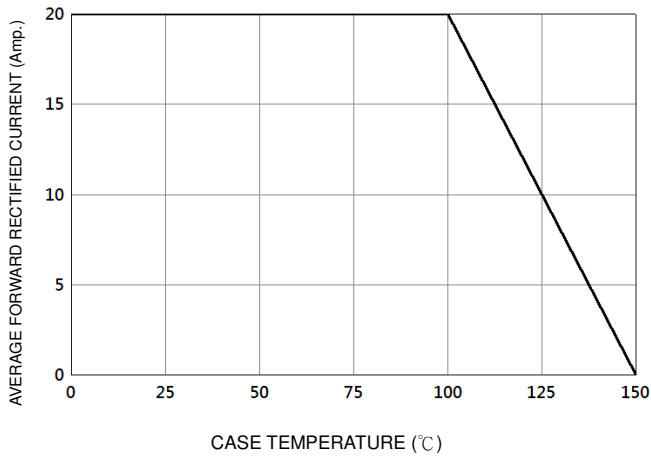


FIG-2 TYPICAL FORWARD CHARACTERISTICS

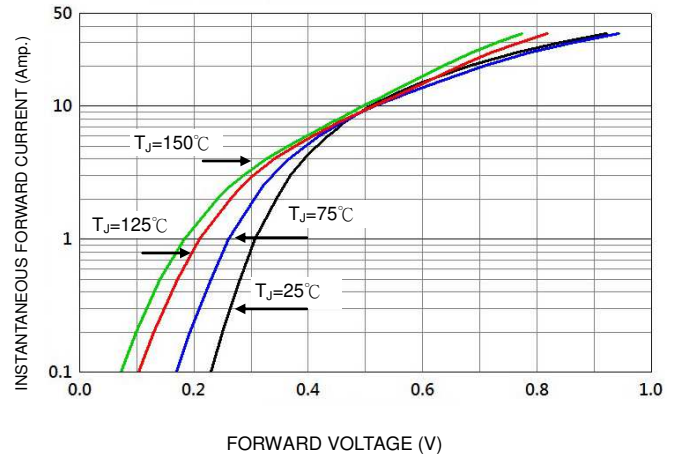


FIG-3 TYPICAL REVERSE CHARACTERISTICS

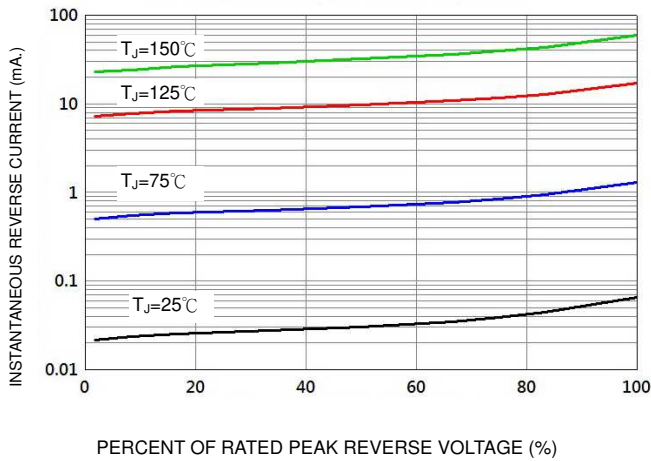


FIG-4 TYPICAL JUNCTION CAPACITANCE

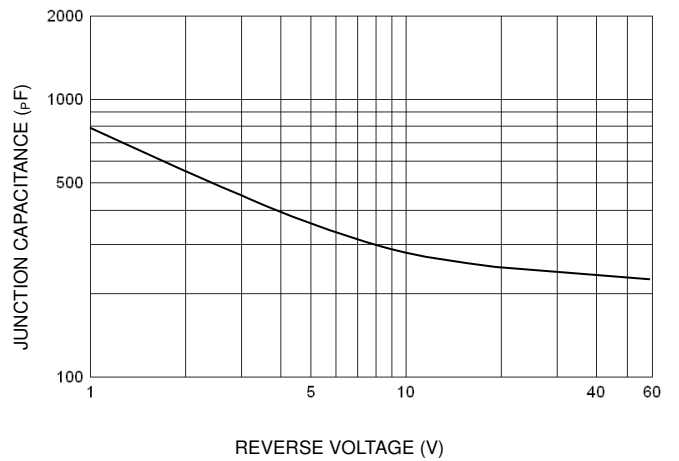
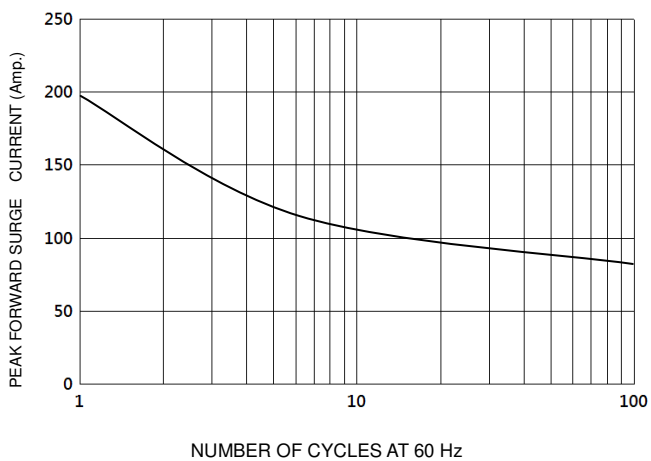


FIG-5 PEAK FORWARD SURGE CURRENT



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